NSN 5961-01-129-3518

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Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-129-3518 **Inclosure Material:** Metal **Overall Length:** 1.107 inches **Overall Height:** 0.340 inches **Overall Width:** 0.700 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-66 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 120.0 collector to base voltage/static/emitter open and 7.0 emitter to base voltage, static, collector open and 75.0 collector-to-emitter, substaining voltage, base open-circuited and 90.0 collector-to-emitter substaining voltage, with specified circuit between base and emitter **Current Rating Per Characteristic:** Between 500.00 milliamperes source cutoff current and 5.00 amperes source cutoff current **Power Rating Per Characteristic:** 35.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No